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Vishay Semiconductors

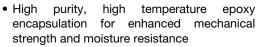
High Performance Schottky Rectifier, 6 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	6 A						
V _R	35 V, 40 V, 45 V						
V _F at I _F	0.53 V						
I _{RM}	7 mA at 125 °C						
T _J max.	175 °C						
E _{AS}	8 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 175 °C T_{.I} operation
- High frequency operation
- · Low forward voltage drop





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES U								
I _{F(AV)}	Rectangular waveform	6	Α					
V_{RRM}	Range	35 to 45	V					
I _{FSM}	t _p = 5 μs sine	690	Α					
V _F	6 A _{pk} , T _J = 125 °C	0.53	V					
T_J	Range	-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-6TQ035S-M3	VS-6TQ040S-M3	VS-6TQ045S-M3	UNITS			
Maximum DC reverse voltage	V_R	35	40	45	W			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 164 °C	6					
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	690	Α			
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	140				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH		8	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.20	Α			

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
Maximum forward voltage drop See fig. 1		6 A	T _{.1} = 25 °C	0.60			
	V _{FM} ⁽¹⁾	12 A	1J=25 C	0.73	V		
	VFM (1)	6 A	T _ 105 °C	0.53	V		
		12 A	T _J = 125 °C	0.64			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Dotad V	0.8	A		
See fig. 2	IRM ('')	T _J = 125 °C	V _R = Rated V _R	7	mA		
Threshold voltage	V _{F(TO)}	T T	$T_J = T_J$ maximum				
Forward slope resistance	r _t	I J = I J maximum					
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	400	pF			
Typical series inductance	L _S	Measured lead to lead 5 n	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	•	T _J , T _{Stg}		-55 to 175	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4		°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	R _{thCS} Mounting surface, smooth, and greased				
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting toward	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
					035S		
Marking device			Case style D ² PAK (TO-263AB)		040S		
				6TQ0	045S		

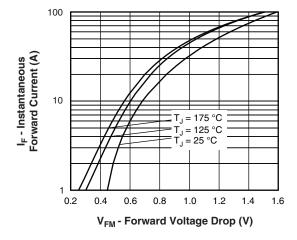


Fig. 1 - Maximum Forward Voltage Drop Characteristics

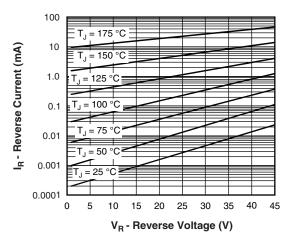


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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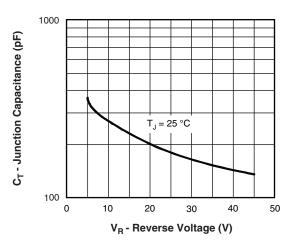


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

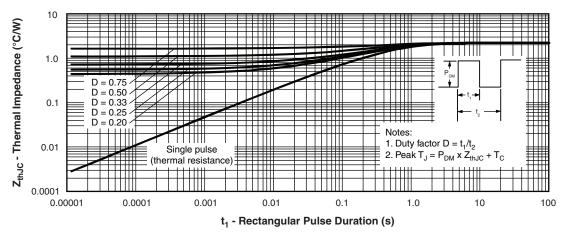


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

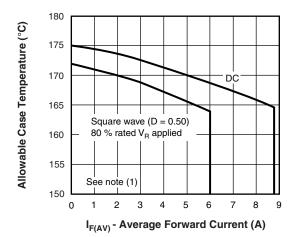


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

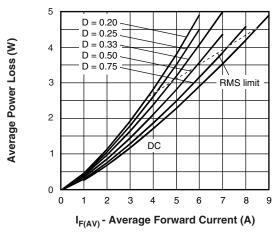


Fig. 6 - Forward Power Loss Characteristics

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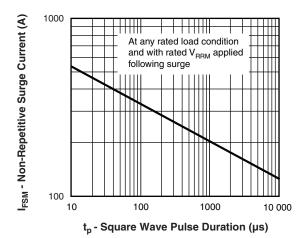


Fig. 7 - Maximum Non-Repetitive Surge Current

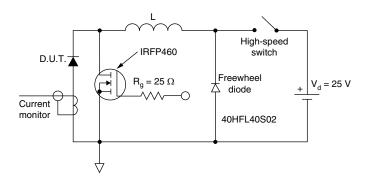


Fig. 8 - Unclamped Inductive Test Circuit

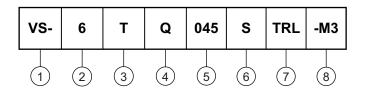
Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at} \ (I_{F(AV)}/D) \ (\text{see fig. 6}); \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \ (1 - D); \ I_R \ \text{at} \ V_{R1} = 80 \ \% \ \text{rated} \ V_R \\ \end{array}$

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Current rating (6 A)

Package: T = TO-220

Schottky "Q" series

040 = 40 VVoltage ratings 045 = 45 V

 $S = D^2PAK (TO-263AB)$

• None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

035 = 35 V

ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-6TQ035S-M3	50	1000	Antistatic plastic tubes						
VS-6TQ035STRR-M3	800	800	13" diameter reel						
VS-6TQ035STRL-M3	800	800	13" diameter reel						
VS-6TQ040S-M3	50	1000	Antistatic plastic tubes						
VS-6TQ040STRR-M3	800	800	13" diameter reel						
VS-6TQ040STRL-M3	800	800	13" diameter reel						
VS-6TQ045S-M3	50	1000	Antistatic plastic tubes						
VS-6TQ045STRR-M3	800	800	13" diameter reel						
VS-6TQ045STRL-M3	800	800	13" diameter reel						

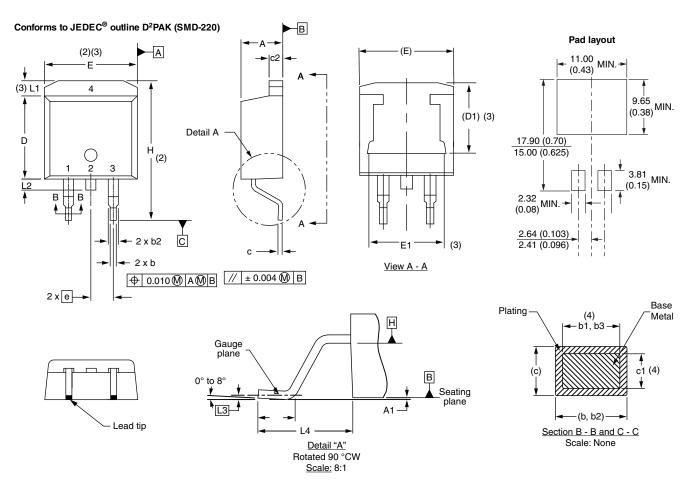
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96164				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES		STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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